

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of: Makoto IWAI, Katsuhiko IMAI and Minoru IMAEDA

Serial No.: 10/594,846

Group Art Unit: 1792

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Conf. No.: 3664

For: GALLIUM NITRIDE SINGLE CRYSTAL GROWING METHOD
AND GALLIUM NITRIDE SINGLE CRYSTAL

Mail Stop Amendment
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

**CERTIFICATION OF EFS
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I hereby certify that this paper is being transmitted via EFS to the Patent
and Trademark Office on December 17, 2009.


Christina M. Bersani

AMENDMENT

Sir:

In response to the Office Action mailed September 17, 2009, please amend the
above-identified application as follows:

Amendments to the Specification are shown on page 2 of this paper.

Amendments to the Claims begin on page 3 of this paper.

Remarks/Arguments begin on page 5 of this paper.